



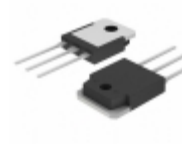
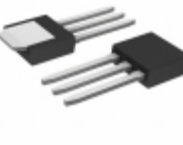

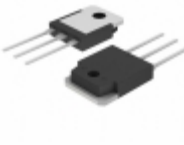

	<b>GP2M010A065F</b>	
	<b>Hersteller-Teilenummer:</b>	GP2M010A065F
	<b>Hersteller / Marke:</b>	Global Power Technologies Group
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 650V 9.5A TO220F
	<b>Datenblätter:</b>	 <a href="#">GP2M010A065F.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 1899 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	GP2M010A065F
Hersteller	Global Power Technologies Group
Beschreibung	MOSFET N-CH 650V 9.5A TO220F
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	1899 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3 Full Pack
Supplier Device-Gehäuse	TO-220F
Verlustleistung (max)	52W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	650V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9.5A (Tc)
Rds On (Max) @ Id, Vgs	820 mOhm @ 4.75A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	36nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1670pF @ 25V
Verpackung	Tube

GP2M010A065F ist neu im Original. Suche GP2M010A065F Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie GP2M010A065F Global Power Technologies Group mit Garantie und Vertrauen. Anfrage GP2M010A065F: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>GP2M010A060H</b> Global Power Technologies Group MOSFET N-CH 600V 10A TO220</p>	 <p><b>GP2M009A090FG</b> Global Power Technologies Group MOSFET N-CH 900V 9A TO220F</p>	 <p><b>GP2M010A065H</b> Global Power Technologies Group MOSFET N-CH 650V 9.5A TO220</p>	 <p><b>GP2M009A090NG</b> Global Power Technologies Group MOSFET N-CH 900V 9A TO3PN</p>
 <p><b>GP2M008A060PGH</b> Global Power Technologies Group MOSFET N-CH 600V 7.5A IPAK</p>	 <p><b>GP2M012A060H</b> Global Power Technologies Group MOSFET N-CH 600V 12A TO220</p>	 <p><b>GP2M012A080NG</b> Global Power Technologies Group MOSFET N-CH 800V 12A TO3PN</p>	 <p><b>GP2M012A060F</b> Global Power Technologies Group MOSFET N-CH 600V 12A TO220F</p>

### heiße Teile

Mehr

⊗ GP2A231LRSA	↔ GP2A25J0000F	⇒ GP2A25J0000F	D GP2A25NJ	↔ GP2A28A1J00F
⊣ GP2A28N1J00F	⊗ GP2AP002A00F	D GP2AP002S00F	⇒ GP2AP003A10F	↔ GP2AP007A00F
⊗ GP2AP008T00F	⊣ GP2AP030A00F	⊗ GP2AP052A00F	↔ GP2AP052A00F	↔ GP2L26K2
D GP2M002A060FG	⊗ GP2M004A060PG	⊣ GP2M004A065FG	⊗ GP2M004A065PG	↔ GP2M005A050PG
⇒ GP2M005A060CG	↔ GP2M005A060FG	⊗ GP2M005A060PGH	⊣ GP2M008A060FGH	↔ GP2M010A060F
↔ GP2M011A090NG	⇒ GP2M012A080NG	D GP2M020A050H	⊗ GP2M020A060N	⊣ GP2S24J0000F
⊗ GP2S27T3	D GP2S27T3J00F	⇒ GP2S27V6	↔ GP2S29SVJ00F	↔ GP2S40JJ000F
⊣ GP2S700HCP	⊗ GP2S700HCP	↔ GP2W0004YP	⇒ GP2W0110YPS	↔ GP2W0112YPOF
⊗ GP2W0118YPS	⊣ GP2W0150YP0F	⊗ GP2W3104XP0F	D GP2W3104YP0F	↔ GP2W3106YP0F
↔ GP2W3152YP0F	⊗ GP2W3172XP0F	⊣ GP2W3270XP0F	⊗ GP2Y0A02YK0F	↔ GP2Y0A02YK0F

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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